# **GP15A THRU GP15M**

### **GLASS PASSIVATED JUNCTION RECTIFIER**

Reverse Voltage - 50 to 1000 Volts Forwa

Forward Current - 1.5 Amperes

# $\begin{array}{c} \textbf{DO-204AC} \\ \textbf{DO-204A$

Dimensions in inches and (millimeters) \* Glass-plastic encapsulation technique is covered by Patent No. 3,996,602 and brazed-lead assembly by Patent No. 3,930,306

SUPERED E

FEATURES

- Underwriters Laboratory Flammability Classification 94V-0
- High temperature metallurgically bonded construction
- Glass passivated cavity-free junction
- Capable of meeting environmental standards of MIL-S-19500
- ◆ 1.5 Ampere operation at T<sub>A</sub>=55°C with no thermal runaway
- Typical I<sub>R</sub> less than 0.1μA
- High temperature soldering guaranteed: 350°C/10 seconds 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

### MECHANICAL DATA

**Case:** JEDEC DO-204AC molded plastic over glass body **Terminals:** Plated axial leads, solderable per MIL-STD-750, Method 2026 **Polarity:** Color band denotes cathode end

Mounting Position: Any

Weight: 0.015 ounce, 0.4 gram

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	GP 15A	GP 15B	GP 15D	GP 15G	GP 15J	GP 15K	GP 15M	UNITS
Maximum repetitive peak reverse voltage	Vrrm	50	100	200	400	600	800	1000	Volts
Maximum RMS voltage	Vrms	35	70	140	280	420	560	700	Volts
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	Volts
Maximum average forward rectified current 0.375" (9.5mm) lead length at TA=55°C	l(AV)	1.5						Amps	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	50.0						Amps	
Maximum instantaneous forward voltage at 1.5A	VF	1.1						Volts	
Maximum full load reverse current, full cycle average 0.375" (9.5mm) lead length atTA=55°C	IR(AV)	100.0						μA	
Maximum reverse currentTA= 25°Cat rated DC blocking voltageTA=150°C	IR	5.0 200.0						μΑ	
Typical reverse recovery time (NOTE 1)	trr	2.0						μs	
Typical junction capacitance (NOTE 2)	CJ	15.0						pF	
Typical thermal resistance (NOTE 3)	R₀ja R₀jl	45.0 20.0						°C/W	
Operating junction and storage temperature range	TJ, TSTG	-65 to +175						°C	

### NOTES:

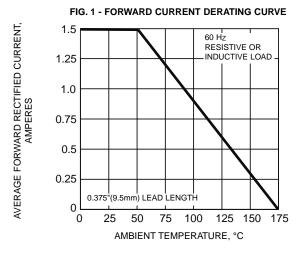
(1) Reverse recovery conditions: I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>rr</sub>=0.25A

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts

(3) Thermal resistance from junction to ambient and from junction to lead at 0.375" (9.5mm) lead length, P.C.B. mounted



### **RATINGS AND CHARACTERISTIC CURVES GP15A THRU GP15M**





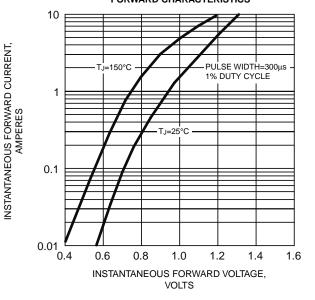


FIG. 5 - TYPICAL JUNCTION CAPACITANCE

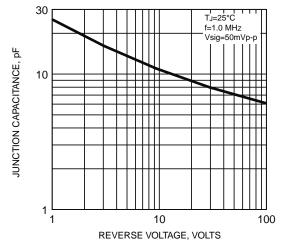
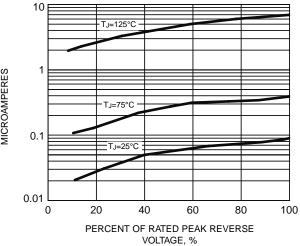


FIG. 2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT 50 TJ=TJ max. PEAK FORWARD SURGE CURRENT, AMPERES 8.3ms SINGLE HALF SINE-WAVE (JEDEC Method) 40 30 20 10 0 100 1 10 NUMBER OF CYCLES AT 60 Hz

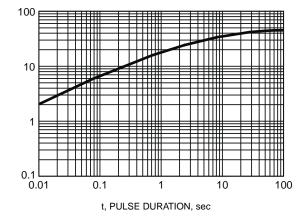






TRANSIENT THERMAL IMPEDANCE (°C/W)

FIG. 6 - TYPICAL TRANSIENT THERMAL IMPEDANCE



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